



Supplementary Materials

Nanostructure of Porous Si and Anodic SiO₂ Surface Passivation for Improved Efficiency Porous Si Solar Cells

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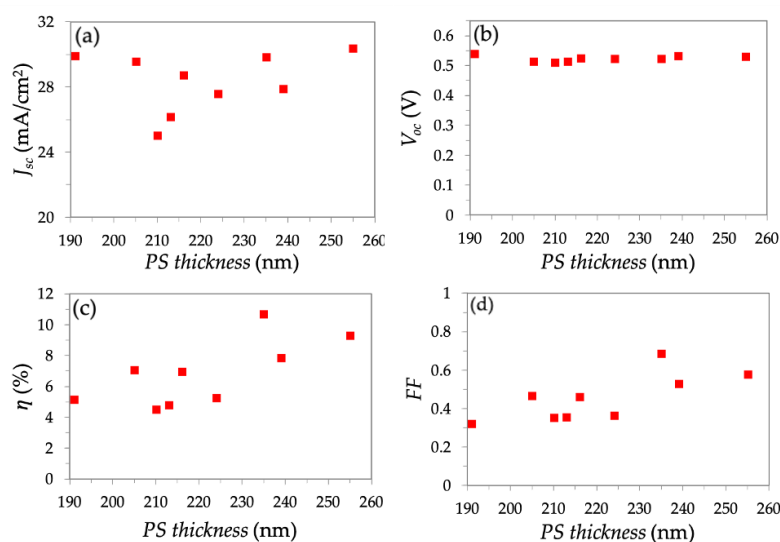


Figure S1. Dependence of PS thickness on PV parameters of PS-2 cells: (a) J_{sc} ; (b) V_{oc} ; (c) η ; (d) FF; (e) FF.



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